CMOS Digital Integrated Circuits Silicon Monolithic

# TC7SZ14F

## 1. Functional Description

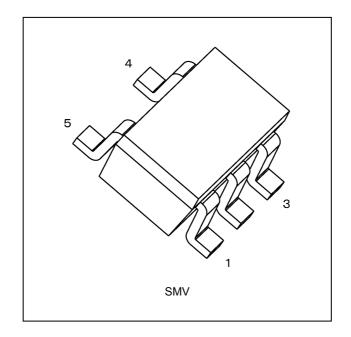
Schmitt Inverter

### 2. Features

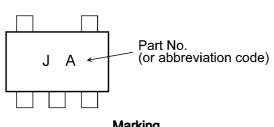
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 2)
- (3) High output current:  $\pm 24$  mA (min) at V<sub>CC</sub> = 3.0 V
- (4) Super high speed operation:  $t_{pd}$  = 3.7 ns (typ.) at V<sub>CC</sub> = 5.0 V, C<sub>L</sub> = 50 pF
- (5) Operation voltage range:  $V_{CC}$  = 1.65 to 5.5 V
- (6) 5.5 V tolerant inputs
- (7) 5.5 V power down protection output
- (8) Matches the performance of TC74LCX series when operated at  $3.3 \text{ V} \text{ V}_{\text{CC}}$
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

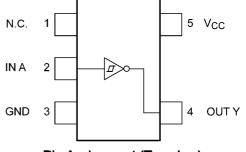
Note 2: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

### 3. Packaging



## 4. Marking and Pin Assignment





Marking



### 5. IEC Logic Symbol



### 6. Truth Table

A	Y
L	Н
Н	L

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 6.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 6.0	V
DC output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 6.0	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	-20	mA
DC output current	I <sub>OUT</sub>		±50	
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	PD		200	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High (H) or Low (L) state. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

## 8. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		1.65 to 5.5	V
		(Note 1)	1.5 to 5.5	
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 2)	0 to 5.5	V
		(Note 3)	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub> (Note 4) -40 to 125		-40 to 125	°C
		(Note 5)	-40 to 85	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

## 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Positive threshold voltage	VP	—		1.65	0.6	1.0	1.4	V
				1.8	0.7	1.1	1.5	
				2.3	1.0	1.4	1.8	
				3.0	1.3	1.75	2.2	]
				4.5	1.9	2.45	3.1	
				5.5	2.2	2.9	3.6	
Negative threshold voltage	V <sub>N</sub>	—		1.65	0.2	0.5	0.8	V
				1.8	0.25	0.55	0.9	
				2.3	0.4	0.75	1.15	
				3.0	0.6	1.0	1.5	1
				4.5	1.0	1.43	2.0	1
				5.5	1.2	1.7	2.4	
Hysteresis voltage	V <sub>H</sub>	_		1.65	0.1	0.48	0.9	V
				1.8	0.15	0.54	1.0	1
				2.3	0.25	0.65	1.1	
				3.0	0.4	0.77	1.2	1
				4.5	0.6	1.01	1.5	1
				5.5	0.7	1.18	1.7	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_N$	I <sub>OH</sub> = -100 μA	1.65	1.55	1.65	_	V
				1.8	1.7	1.8	_	
				2.3	2.2	2.3	_	
				3.0	2.9	3.0	_	1
				4.5	4.4	4.5	_	1
			I <sub>OH</sub> = -4 mA	1.65	1.29	1.52	_	
			I <sub>OH</sub> = -8 mA	2.3	1.9	2.15	_	1
			I <sub>OH</sub> = -16 mA	3.0	2.4	2.8	_	
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	_	
			I <sub>OH</sub> = -32 mA	4.5	3.8	4.2	_	1
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>P</sub>	I <sub>OL</sub> = 100 μA	1.65	_	0.0	0.1	V
				1.8	_	0.0	0.1	
				2.3	_	0.0	0.1	1
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	1
			I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3	
			I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	1
			I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	
			I <sub>OL</sub> = 32 mA	4.5		0.22	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±1	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	—	—	1	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	_	1	μA

## 9.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition	on	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	—		1.65	0.65	1.4	V
				1.8	0.7	1.5	
				2.3	1.0	1.8	1
				3.0	1.3	2.2	1
				4.5	1.9	3.1	
				5.5	2.2	3.6	1
Negative threshold voltage	V <sub>N</sub>	—		1.65	0.2	0.8	V
				1.8	0.25	0.9	
				2.3	0.4	1.15	1
				3.0	0.6	1.5	1
				4.5	1.0	2.0	
				5.5	1.2	2.4	1
Hysteresis voltage	V <sub>H</sub>	_		1.65	0.1	1.0	V
				1.8	0.15	1.0	
				2.3	0.25	1.1	1
				3.0	0.4	1.2	1
				4.5	0.6	1.5	1
				5.5	0.7	1.7	1
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_N$	I <sub>OH</sub> = -100 μA	1.65	1.55		V
				1.8	1.7	_	
				2.3	2.2	_	1
				3.0	2.9		1
				4.5	4.4	_	1
			I <sub>OH</sub> = -4 mA	1.65	1.29		1
			I <sub>OH</sub> = -8 mA	2.3	1.9		1
			I <sub>OH</sub> = -16 mA	3.0	2.4	_	1
			I <sub>OH</sub> = -24 mA	3.0	2.3		1
			I <sub>OH</sub> = -32 mA	4.5	3.8	_	1
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>P</sub>	I <sub>OL</sub> = 100 μA	1.65	_	0.1	V
				1.8	_	0.1	1
				2.3	—	0.1	1
				3.0	_	0.1	1
				4.5	_	0.1	1
			I <sub>OL</sub> = 4 mA	1.65	—	0.24	1
			I <sub>OL</sub> = 8 mA	2.3	_	0.3	1
			I <sub>OL</sub> = 16 mA	3.0	_	0.4	1
			I <sub>OL</sub> = 24 mA	3.0	_	0.55	1
			I <sub>OL</sub> = 32 mA	4.5	_	0.55	1
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±10	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	_	10	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5		10	μA

## 9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	on	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	—		1.65	0.65	1.4	V
				1.8	0.7	1.5	1
				2.3	1.0	1.8	1
				3.0	1.3	2.2	1
				4.5	1.9	3.1	
				5.5	2.2	3.6	1
Negative threshold voltage	V <sub>N</sub>	_		1.65	0.2	0.8	V
				1.8	0.25	0.9	
				2.3	0.4	1.15	1
				3.0	0.6	1.5	1
				4.5	1.0	2.0	
				5.5	1.2	2.4	1
Hysteresis voltage	V <sub>H</sub>	_		1.65	0.1	1.0	V
				1.8	0.15	1.0	
				2.3	0.25	1.1	1
				3.0	0.4	1.2	
				4.5	0.6	1.5	
				5.5	0.7	1.7	1
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>N</sub>	I <sub>OH</sub> = -100 μA	1.65	1.55	_	V
				1.8	1.7	_	
				2.3	2.2	_	
				3.0	2.9	_	
				4.5	4.4	_	
			I <sub>OH</sub> = -4 mA	1.65	0.95	_	
			I <sub>OH</sub> = -8 mA	2.3	1.7	_	
			I <sub>OH</sub> = -16 mA	3.0	2.2		
			I <sub>OH</sub> = -24 mA	3.0	2.0	_	1
			I <sub>OH</sub> = -32 mA	4.5	3.4	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>P</sub>	I <sub>OL</sub> = 100 μA	1.65		0.1	V
				1.8		0.1	1
				2.3		0.1	
				3.0		0.1	1
				4.5		0.1	1
			I <sub>OL</sub> = 4 mA	1.65		0.7	1
			I <sub>OL</sub> = 8 mA	2.3		0.45	1
			I <sub>OL</sub> = 16 mA	3.0		0.6	1
			I <sub>OL</sub> = 24 mA	3.0		0.8	1
			I <sub>OL</sub> = 32 mA	4.5		0.8	1
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5		±20.0	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	_	100	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5		100	μΑ

Note: For devices with the ordering part number ending in J(CT.

## 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$R_L = 1 M\Omega$	$1.8\pm0.15$	15	2.0	9.1	15.0	ns
				$2.5\pm0.2$		1.0	5.0	9.0	
				$3.3\pm0.3$		1.0	3.7	6.3	
				$5.0\pm0.5$		0.5	3.1	5.2	
			R <sub>L</sub> = 500 Ω	$\textbf{3.3}\pm\textbf{0.3}$	50	1.5	4.4	7.2	ns
				$5.0\pm0.5$		0.5	3.7	5.9	
Input capacitance	C <sub>IN</sub>		—	0 to 5.5	_	_	4	_	pF
Power dissipation	C <sub>PD</sub>	(Note 1)	—	3.3	_	_	24	—	pF
capacitance				5.5		_	30	_	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

## 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$R_L = 1 M\Omega$	$1.8\pm0.15$	15	2.0	15.6	ns
			$2.5\pm0.2$		1.0	9.5	
			$\textbf{3.3}\pm\textbf{0.3}$		1.0	6.5	
			$5.0\pm0.5$	]	0.5	5.5	
		R <sub>L</sub> = 500 Ω	$3.3\pm0.3$	50	1.5	7.5	ns
			$5.0\pm0.5$		0.8	6.2	

#### 9.6. AC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

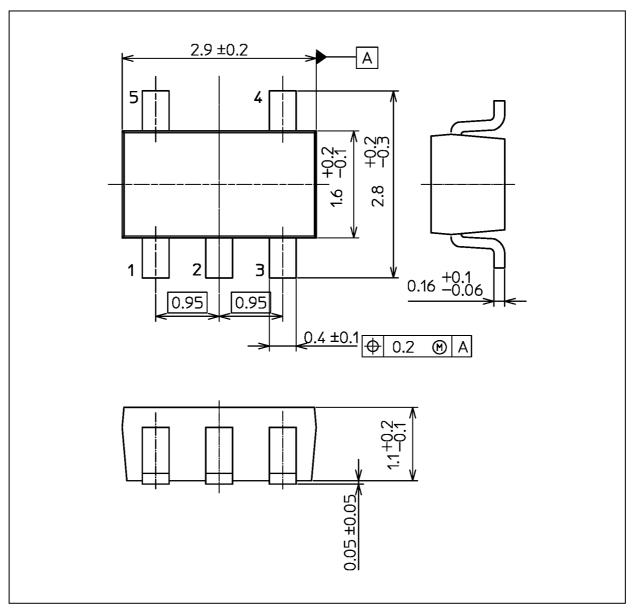
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$R_L = 1 M\Omega$	$1.8\pm0.15$	15	2.0	17.5	ns
			$2.5\pm0.2$		1.0	10.5	
			$\textbf{3.3}\pm\textbf{0.3}$		1.0	7.5	
			$5.0\pm0.5$		0.5	6.5	
		R <sub>L</sub> = 500 Ω	$\textbf{3.3}\pm\textbf{0.3}$	50	1.5	8.5	ns
			$5.0\pm0.5$		0.8	7.0	

Note: For devices with the ordering part number ending in J(CT.



### **Package Dimensions**

Unit: mm



#### Weight: 14 mg (typ.)

	Package Name(s)	
JEDEC: SOT-25		
Nickname: SMV		

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